ΡΛΝ	JIT
	SEMI
	CONDUCTOR

### 60V N-Channel Enhancement Mode MOSFET

Voltage

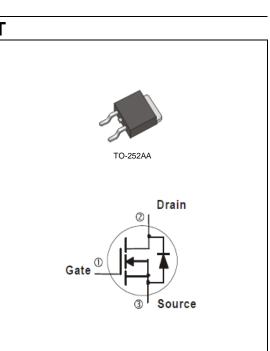
## 60 V Current 25 A

Features

- R<sub>DS(ON)</sub>, V<sub>GS</sub>@10V,I<sub>D</sub>@15A<34mΩ
- R<sub>DS(ON)</sub>, V<sub>GS</sub>@4.5V,I<sub>D</sub>@10A<40mΩ
- High switching speed
- Improved dv/dt capability
- Low reverse transfer capacitance
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

#### **Mechanical Data**

- Case : TO-252AA Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.0104 ounces, 0.297grams



## **Maximum Ratings and Thermal Characteristics** ( $T_A=25^{\circ}C$ unless otherwise noted)

PARAMET	ER	SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V <sub>DS</sub>	60	V
Gate-Source Voltage		V <sub>GS</sub>	<u>+</u> 20	V
Continuous Drain Current	T <sub>C</sub> =25°C		25	A
	T <sub>C</sub> =100°C	I <sub>D</sub>	16	
Pulsed Drain Current <sup>(Note 1)</sup>	T <sub>C</sub> =25°C	I <sub>DM</sub>	100	
Power Dissipation	T <sub>C</sub> =25°C	D-	48.4	W
	T <sub>C</sub> =100°C	PD	24.2	
	T <sub>A</sub> =25°C		5.5	А
Continuous Drain Current	T <sub>A</sub> =70°C	I <sub>D</sub>	4.4	А
Power Dissipation	T <sub>A</sub> =25°C		2.4	W
Power Dissipation	T <sub>A</sub> =70°C	PD	1.6	
Single Pulse Avalanche Energy (Note 6)		E <sub>AS</sub>	24	mJ
Operating Junction and Storage Temperature Range		T <sub>J</sub> ,T <sub>STG</sub>	-55~175	°C
Typical Thermal resistance <sup>(Note 4,5)</sup>	Junction to Case	$R_{\theta JC}$	3.1	00000
	Junction to Ambient	R <sub>θJA</sub>	62.5	°C/W

• Limited only By Maximum Junction Temperature



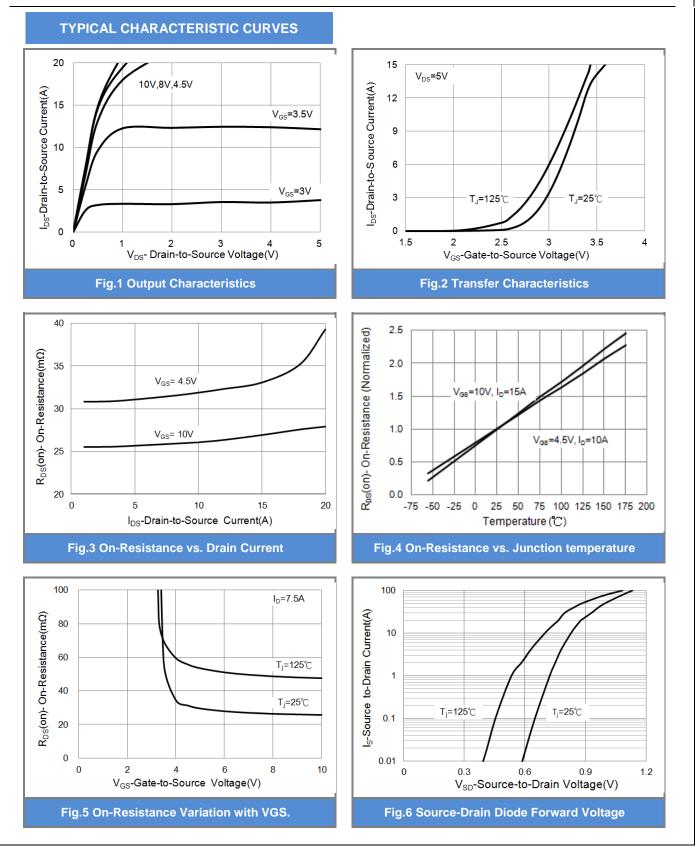
### **Electrical Characteristics** ( $T_A=25^{\circ}C$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static		·				
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V,I <sub>D</sub> =250uA	60	-	-	V
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS}$ , $I_{D}=250$ uA	1.0	1.83	2.5	V
Drain-Source On-State Resistance	_	V <sub>GS</sub> =10V,I <sub>D</sub> =15A	-	28	34	mΩ
	R <sub>DS(on)</sub>	V <sub>GS</sub> =4.5V,I <sub>D</sub> =10A		33	40	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =60V,V <sub>GS</sub> =0V	-	-	1.0	uA
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = <u>+</u> 20V,V <sub>DS</sub> =0V	-	-	<u>+</u> 100	nA
Dynamic (Note 7)		·				
Total Gate Charge	Qg		-	20	-	nC
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}$ =30V, I <sub>D</sub> =20A, $V_{GS}$ =10V <sup>(Note 1,2)</sup>	-	3.8	-	
Gate-Drain Charge	Q <sub>gd</sub>		-	3.9	-	
Input Capacitance	Ciss	V <sub>DS</sub> =25V, V <sub>GS</sub> =0V, f=1.0MHZ	-	1173	-	pF
Output Capacitance	Coss		-	63	-	
Reverse Transfer Capacitance	Crss		-	44	-	
Turn-On Delay Time	td <sub>(on)</sub>		-	7.1	-	
Turn-On Rise Time	tr	$V_{DD}$ =15V, I <sub>D</sub> =1A, V <sub>GS</sub> =10V, R <sub>G</sub> =6Ω (Note 1,2)	-	25	-	-
Turn-Off Delay Time	td <sub>(off)</sub>		-	31	-	ns
Turn-Off Fall Time	t <sub>f</sub>		-	20	-	
Drain-Source Diode						
Maximum Continuous Drain-Source					05	•
Diode Forward Current	I <sub>S</sub>		-	-	25	A
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =1A,V <sub>GS</sub> =0V	-	0.72	1.2	V

NOTES :

- 1. Pulse width</br>
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Repetitive rating, pulse width limited by junction temperature TJ(MAX)=150°C. Ratings are based on low frequency and duty cycles to keep initial TJ =25°C.
- 4. The maximum current rating is package limited.
- 5.  $R_{\Theta JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch<sup>2</sup> with 2oz.square pad of copper.
- 6. The test condition is L=0.1mH,  $I_{\text{AS}}{=}22\text{A},\,V_{\text{DD}}{=}25\text{V},\,V_{\text{GS}}{=}10\text{V}$
- 7. Guaranteed by design, not subject to production testing.

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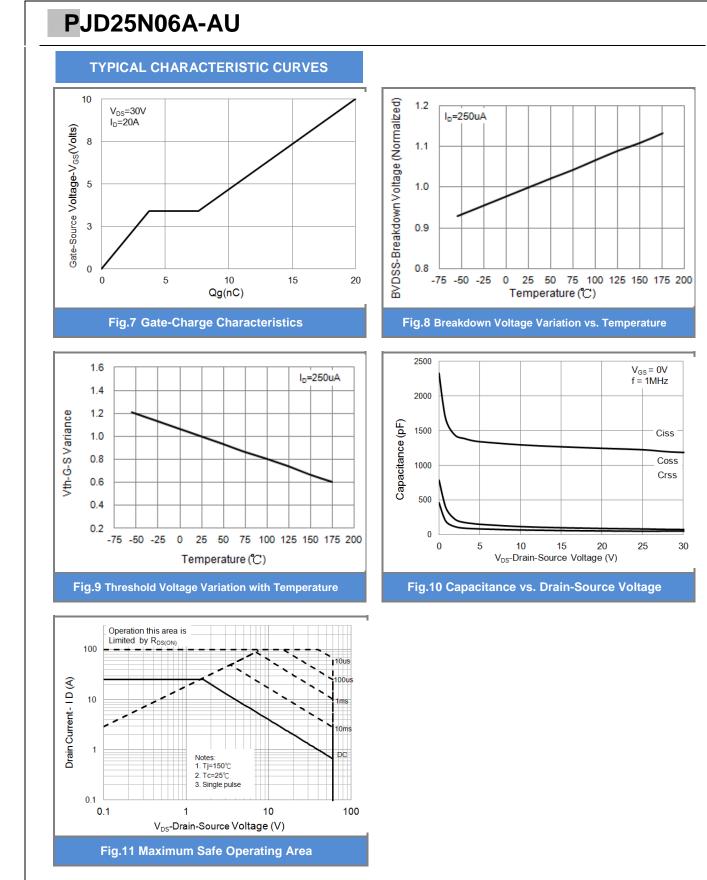


PJD25N06A-AU



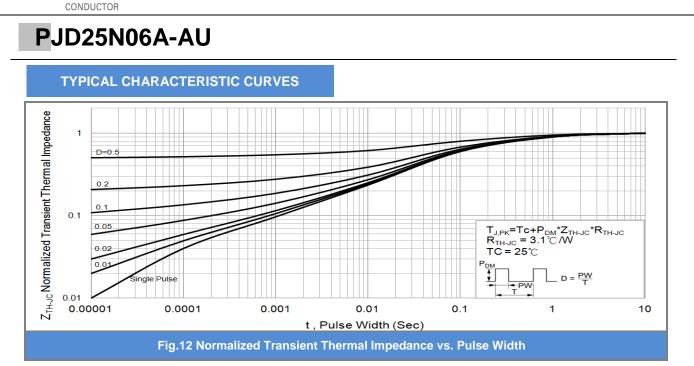
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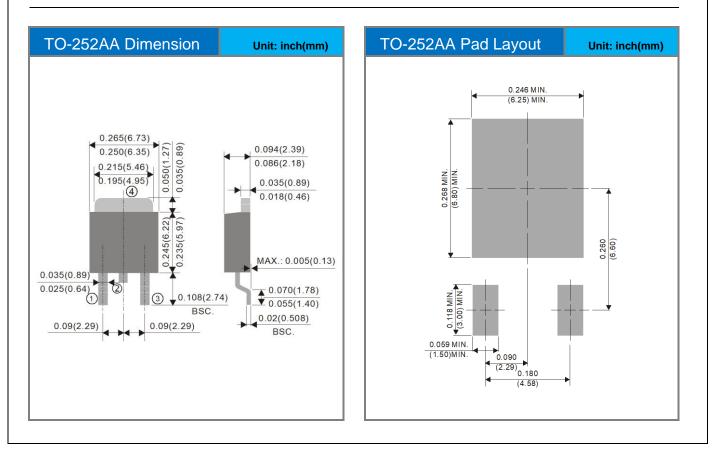




#### PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJD25N06A-AU_L2_000A1	TO-252AA	3,000pcs / 13" reel	D25N06A	Halogen free

#### **Packaging Information & Mounting Pad Layout**





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